NSN 5961-01-372-8539

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-372-8539 **Inclosure Material:** Plastic **Overall Length:** 1.190 inches **Overall Diameter:** 0.410 inches Lens Transparency: Transparent all light emitting diode **Component Name And Quantity:** 7 light emitting diode **Mounting Method:** Press fit **Semiconductor Material:** Gallium phosphide all light emitting diode Voltage Rating In Volts Per Characteristic: 120.0 reverse voltage, instantaneous all light emitting diode **Current Rating Per Characteristic:** 12.00 milliamperes collector current, dc of standard range all light emitting diode **Power Rating Per Characteristic:** 1.3 watts any acceptable preset all light emitting diode **Color Tone Produced Per Source:** Green semiconductor all light emitting diode **Maximum Operating Tempurature Per Measurement Point:** 50.0 degrees celsius ambient air **Special Features:** All light emitting diode junction pattern arrangement: pn **Terminal Type And Quantity:** 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: